

MMBT918LT1

VHF/UHF Transistor

NPN Silicon

Features

- Pb-Free Package May be Available. The G-Suffix Denotes a Pb-Free Lead Finish

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	15	Vdc
Collector-Base Voltage	V_{CBO}	30	Vdc
Emitter-Base Voltage	V_{EBO}	3.0	Vdc
Collector Current - Continuous	I_C	50	mA _{dc}

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	225	mW
		1.8	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	300	mW
		2.4	mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

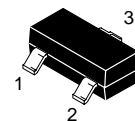
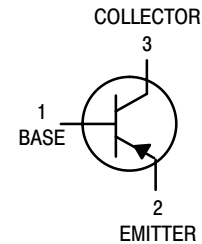
1. FR-5 = 1.0 x 0.75 x 0.062 in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.



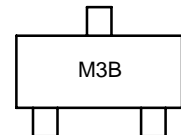
ON Semiconductor®

<http://onsemi.com>



SOT-23 (TO-236AF)
CASE 318
Style 6

MARKING DIAGRAM



M3B = Specific Device Code

ORDERING INFORMATION

Device	Package	Shipping†
MMBT918LT1	SOT-23	3000 / Tape & Reel
MMBT918LT1G	SOT-23	3000 / Tape & Reel
MMBTA92LT3	SOT-23	10000 / Tape & Reel

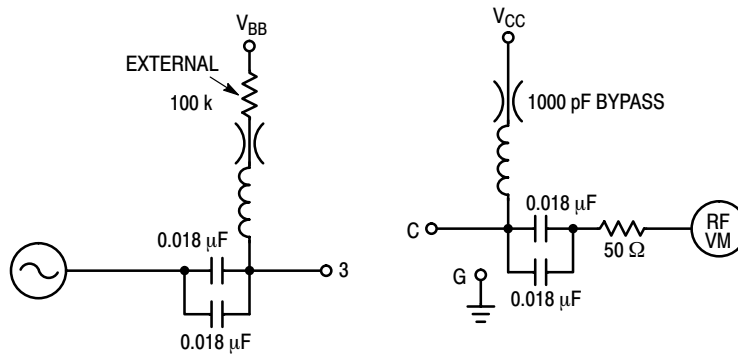
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Breakdown Voltage ($I_C = 3.0\text{ mA}$, $I_B = 0$)	$V_{(BR)CEO}$	15	–	Vdc
Collector–Base Breakdown Voltage ($I_C = 1.0\text{ }\mu\text{A}$, $I_E = 0$)	$V_{(BR)CBO}$	30	–	Vdc
Emitter–Base Breakdown Voltage ($I_E = 10\text{ }\mu\text{A}$, $I_C = 0$)	$V_{(BR)EBO}$	3.0	–	Vdc
Collector Cutoff Current ($V_{CB} = 15\text{ Vdc}$, $I_E = 0$)	I_{CBO}	–	50	nAdc
ON CHARACTERISTICS				
DC Current Gain ($I_C = 3.0\text{ mA}$, $V_{CE} = 1.0\text{ Vdc}$)	h_{FE}	20	–	–
Collector–Emitter Saturation Voltage ($I_C = 10\text{ mA}$, $I_B = 1.0\text{ mA}$)	$V_{CE(sat)}$	–	0.4	Vdc
Base–Emitter Saturation Voltage ($I_C = 10\text{ mA}$, $I_B = 1.0\text{ mA}$)	$V_{BE(sat)}$	–	1.0	Vdc
SMALL–SIGNAL CHARACTERISTICS				
Current–Gain – Bandwidth Product ($I_C = 4.0\text{ mA}$, $V_{CE} = 10\text{ Vdc}$, $f = 100\text{ MHz}$)	f_T	600	–	MHz
Output Capacitance ($V_{CB} = 0\text{ Vdc}$, $I_E = 0$, $f = 1.0\text{ MHz}$) ($V_{CB} = 10\text{ Vdc}$, $I_E = 0$, $f = 1.0\text{ MHz}$)	C_{obo}	– –	3.0 1.7	pF
Input Capacitance ($V_{EB} = 0.5\text{ Vdc}$, $I_C = 0$, $f = 1.0\text{ MHz}$)	C_{ibo}	–	2.0	pF
Noise Figure ($I_C = 1.0\text{ mA}$, $V_{CE} = 6.0\text{ Vdc}$, $R_S = 50\text{ }\Omega$, $f = 60\text{ MHz}$) (Figure 1)	NF	–	6.0	dB
Power Output ($I_C = 8.0\text{ mA}$, $V_{CB} = 15\text{ Vdc}$, $f = 500\text{ MHz}$)	P_{out}	30	–	mW
Common–Emitter Amplifier Power Gain ($I_C = 6.0\text{ mA}$, $V_{CB} = 12\text{ Vdc}$, $f = 200\text{ MHz}$)	G_{pe}	11	–	dB

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NF TEST CONDITIONS

$I_C = 1.0 \text{ mA}$
 $V_{CE} = 6.0 \text{ VOLTS}$
 $R_S = 50 \Omega$
 $f = 60 \text{ MHz}$

G_{pe} TEST CONDITIONS

$I_C = 6.0 \text{ mA}$
 $V_{CE} = 12 \text{ VOLTS}$
 $f = 200 \text{ MHz}$

Figure 1. NF, G_{pe} Measurement Circuit 20–200

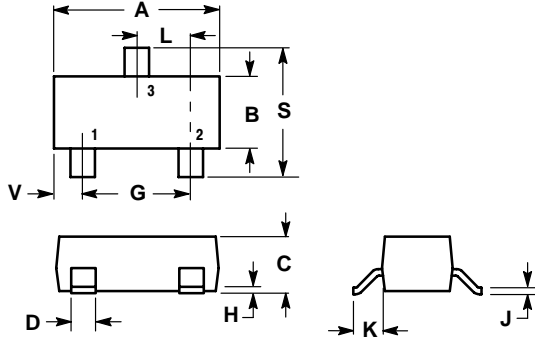
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PACKAGE DIMENSIONS

SOT-23 (TO-236)
CASE 318-08
ISSUE AH

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. 318-03 AND -07 OBSOLETE, NEW STANDARD 318-08.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

STYLE 6:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

SOLDERING FOOTPRINT*

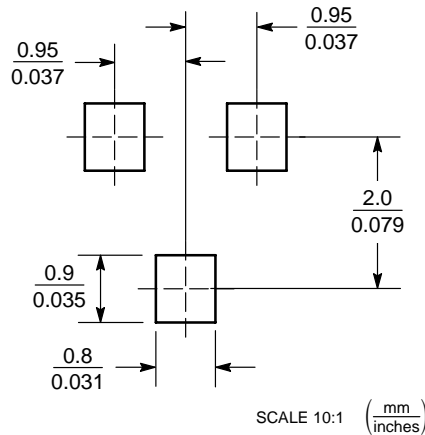



Figure 2. SOT-23

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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